

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

Product Specification

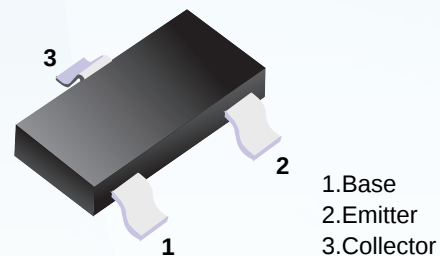
▶ Domestic	Part Number	MMBTH10
▶ Overseas	Part Number	MMBTH10
▶ Equivalent	Part Number	MMBTH10

EV is the abbreviation of name EVVO

■ NPN Transistors

■ Features

- Collector Current Capability $I_C=0.05A$
- Collector Emitter Voltage $V_{CEO}=25V$



■ Simplified outline(SOT-23)

■ Classification of hfe

Marking	3EM
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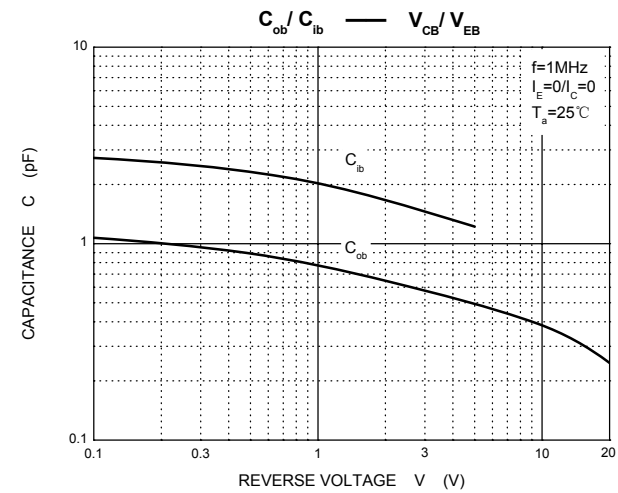
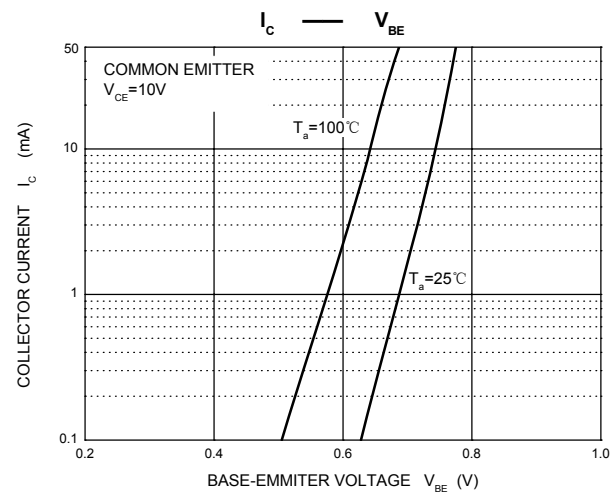
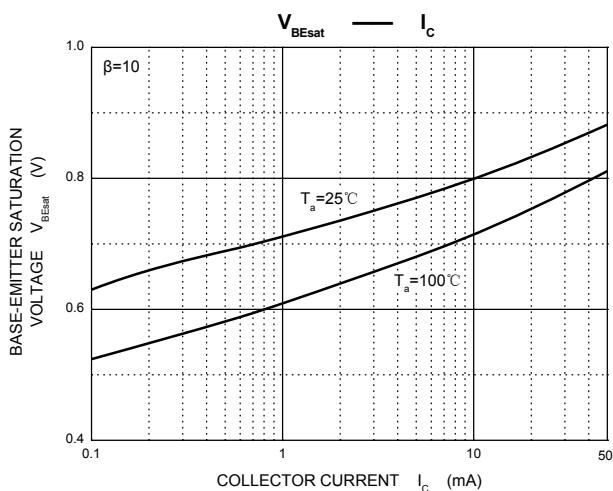
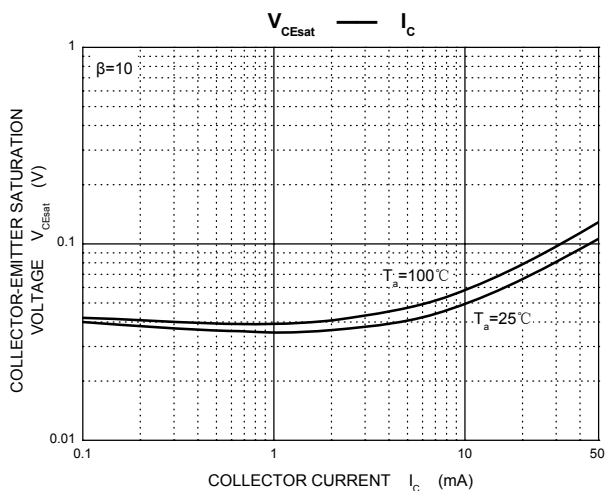
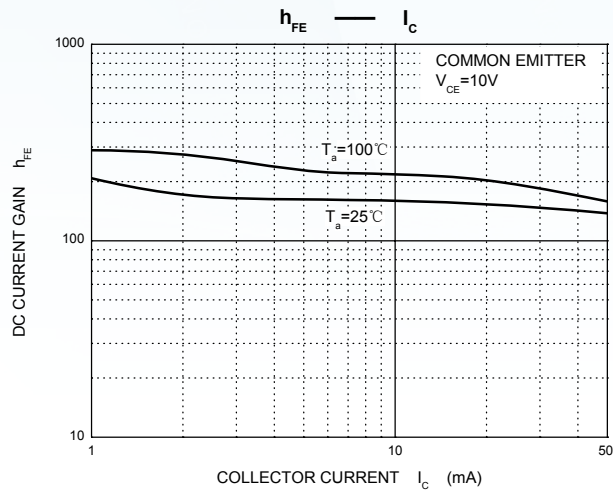
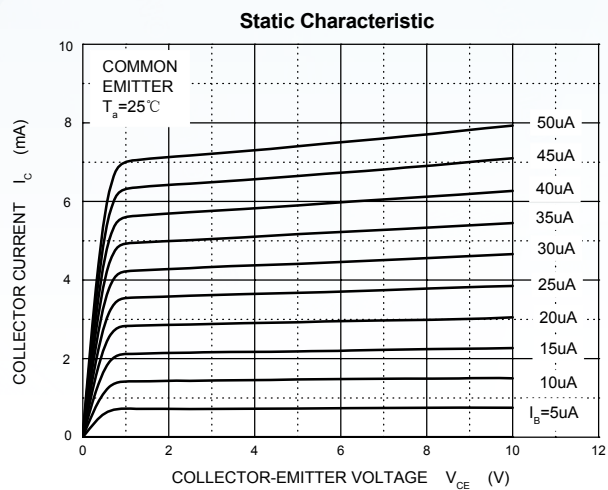
■ Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CBO}	30	V
Collector - Emitter Voltage	V_{CEO}	25	
Emitter - Base Voltage	V_{EBO}	3	
Collector Current - Continuous	I_C	0.05	A
Collector Power Dissipation	P_C	225	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	$^{\circ}C/W$
Junction Temperature	T_J	150	$^{\circ}C$
Storage Temperature Range	T_{stg}	-55 to +150	

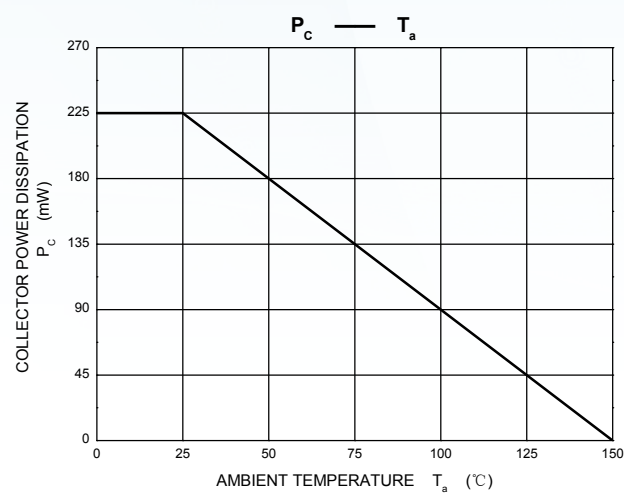
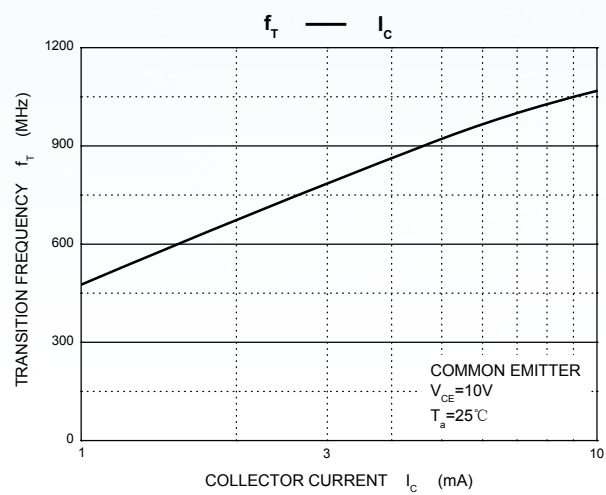
■ Electrical Characteristics $T_a = 25^{\circ}C$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V_{CBO}	$I_C = 100 \mu A, I_E = 0$	30			V
Collector- emitter breakdown voltage	V_{CEO}	$I_C = 1 mA, I_B = 0$	25			
Emitter - base breakdown voltage	V_{EBO}	$I_E = 10 \mu A, I_C = 0$	3			
Collector-base cut-off current	I_{CBO}	$V_{CB} = 25 V, I_E = 0$			100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = 2 V, I_C = 0$			100	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 4 mA, I_B = 0.4 mA$			0.5	V
Base - emitter saturation voltage	$V_{BE(sat)}$	$I_C = 4 mA, I_B = 0.4 mA$			1.2	
Base - emitter saturation voltage	V_{BE}	$V_{CE} = 10 V, I_C = 4 mA$			0.95	
DC current gain	h_{FE}	$V_{CE} = 10 V, I_C = 4 mA$	60			
Collector output capacitance	C_{ob}	$V_{CB} = 10 V, I_E = 0, f = 1 MHz$			0.7	pF
Transition frequency	f_T	$V_{CE} = 10 V, I_C = 4 mA, f = 100 MHz$	650			MHz

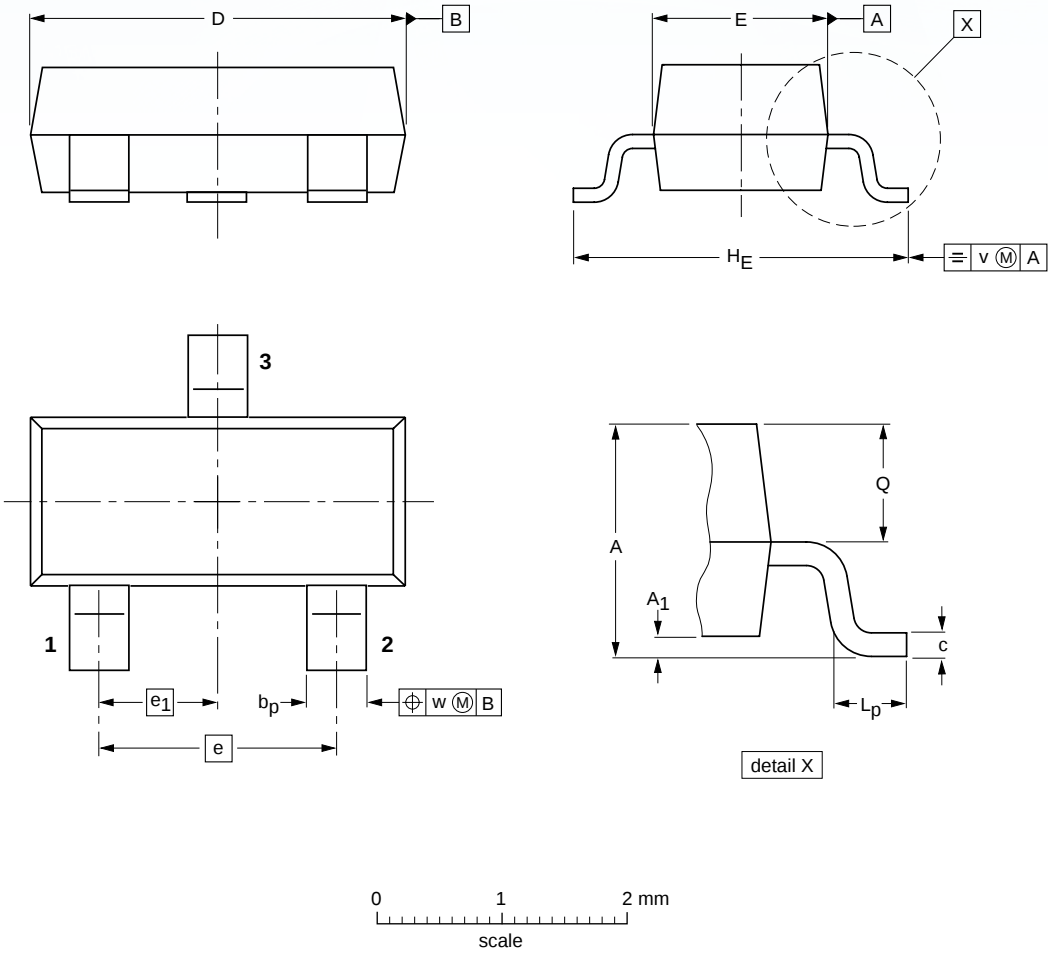
Typical Characteristics



■ Typical Characteristics



■ SOT-23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

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